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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Inventor: Yukihiro INOUE

Group Art Unit: 2811

Appln. No.: 09/768,556

Examiner: S. Gebremariam

Filed: January 25, 2001

For: SEMICONDUCTOR DEVICE

AMENDMENT UNDER 37 CFR § 1.116

Assistant Commissioner of Patents  
Washington, D.C. 20231

Sir:

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TECHNOLOGY CENTER 2800

In response to the Final Rejection dated August 9, 2002,  
please amend the above-captioned application as follows:

IN THE DRAWINGS:

Proposed changes to Figs. 3A-3D are submitted herewith, with  
a Letter to the Official Draftsman.

IN THE CLAIMS:

Kindly amend claims 9 and 10 as follows (Exhibit I contains  
a marked up version):

9. (Amended) A semiconductor device comprising:  
a gate insulator film of a transistor formed in a  
predetermined region on a region of a first conductivity type;

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